

TOSHIBA PHOTOCOUPLER PHOTO RELAY

TLP594G

MODEMS

PBXes

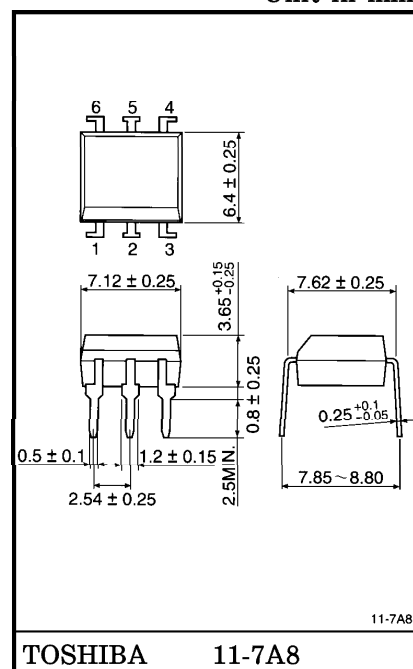
TELECOMMUNICATIONS

The TOSHIBA TLP594G consists of a gallium arsenide infrared emitting diode optically coupled to a photo-MOS FET in a DIP (DIP6), which is suitable for equipment for high tech communications, including modems.

The TLP594G complies with FCC part 68 rules with current limiting function.

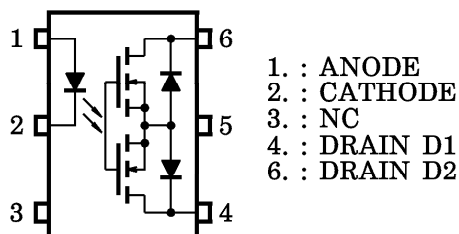
- Peak Off-State Voltage : 350 V (min)
- Trigger LED Current : 3 mA (max)
- On-State Current : 120 mA (max)
- Load Current Limiting : 150 mA~300 mA (t = 5 ms)
- On-State Resistance : 35 Ω (max)
- Isolation Voltage : 2500 Vrms (min)
- UL Recognized : UL1577, File No. E67349

Unit in mm

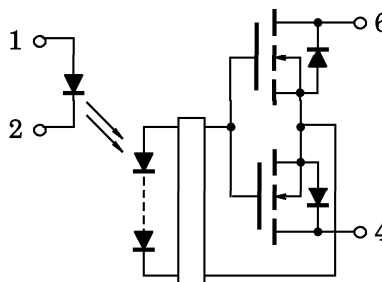


Weight : 0.4 g

PIN CONFIGURATION (TOP VIEW)



SCHEMATIC



980910EBC1

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MAXIMUM RATINGS (Ta = 25°C)

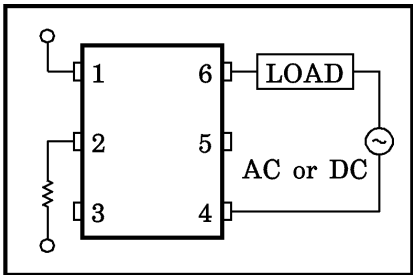
CHARACTERISTIC		SYMBOL	RATING	UNIT
LED	Forward Current	IF	50	mA
	Forward Current Derating (Ta ≥ 25°C)	ΔIF / °C	−0.5	mA / °C
	Peak Forward Current (100 μs pulse, 100 pps)	IFP	1	A
	Reverse Voltage	VR	5	V
	Junction Temperature	Tj	125	°C
DETECTOR	Off-State Output Terminal Voltage	VOFF	350	V
	On-State RMS Current	ION	120	mA
	On-State Current Derating (Ta ≥ 25°C)	ΔION / °C	−1.2	mA / °C
	Junction Temperature	Tj	125	°C
Storage Temperature Range		Tstg	−55~125	°C
Operating Temperature Range		Topr	−40~85	°C
Lead Soldering Temperature (10 s)		Tsol	260	°C
Isolation Voltage (AC, 1 min., R.H. ≤ 60%) (Note 1)		BVS	2500	Vrms

(Note 1) : Device considered a two-terminal device : pins 1, 2 and 3 shorted together and pins 4, 5 and 6 shorted together.

RECOMMENDED OPERATING CONDITIONS

CHARACTERISTIC	SYMBOL	MIN	TYP.	MAX	UNIT
Supply Voltage	VDD	—	—	280	V
Forward Current	IF	5	7.5	25	mA
On-State Current	ION	—	—	120	mA
Operating Temperature	Topr	−20	—	65	°C

CIRCUIT CONNECTIONS



INDIVIDUAL ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
LED	Forward Voltage	V_F	$I_F = 10 \text{ mA}$	1.0	1.15	1.3	V
	Reverse Current	I_R	$V_R = 5 \text{ V}$	—	—	10	μA
	Capacitance	C_T	$V = 0, f = 1 \text{ MHz}$	—	30	—	pF
DETECTOR	Off-State Current	I_{OFF}	$V_{OFF} = 350 \text{ V}$	—	—	1	μA
	Capacitance	C_{OFF}	$V = 0, f = 1 \text{ MHz}$	—	40	—	pF

COUPLED ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
Trigger LED Current	I_{FT}	$I_{ON} = 120 \text{ mA}$	—	—	3	mA
On-State Resistance	R_{ON}	$I_{ON} = 120 \text{ mA}, I_F = 5 \text{ mA}$	—	22	35	Ω
		$I_{ON} = 20 \sim 120 \text{ mA}, I_F = 5 \text{ mA}$	—	26	40	Ω
Load Current Limiting	I_{LIM}	$I_F = 5 \text{ mA}, V_{DD} = 5 \text{ V}, t = 5 \text{ ms}$	150	—	300	mA

ISOLATION CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
Capacitance Input to Output	C_S	$V_S = 0, f = 1 \text{ MHz}$	—	0.8	—	pF
Isolation Resistance	R_S	$V_S = 500 \text{ V}, R.H. \leq 60\%$	5×10^{10}	10^{14}	—	Ω
Isolation Voltage	BV_S	AC, 1 minute	2500	—	—	V_{rms}
		AC, 1 second, in oil	—	5000	—	
		DC, 1 minute, in oil	—	5000	—	Vdc

SWITCHING CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
Turn-on Time	t_{ON}	$R_L = 200 \Omega$ (Note 2)	—	—	1	ms
Turn-off Time	t_{OFF}	$V_{DD} = 20 \text{ V}, I_F = 5 \text{ mA}$	—	—	1	

(Note 2) : SWITCHING TIME TEST CIRCUIT

